

Vishay Siliconix

P-Channel 30-V (D-S) MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	R_{DS(on)} (Ω)	I _D (A)			
- 30	0.014 at V _{GS} = - 10 V	- 11.5			
	0.022 at V _{GS} = - 4.5 V	- 9.2			

FEATURES

- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET[®] Power MOSFETs
- 100 % Rg Tested
- Compliant to RoHS Directive 2002/95/EC •

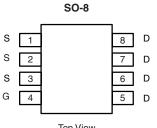
GC

s

D

P-Channel MOSFET





Top View

Ordering Information: Si4825DY-T1-E3 (Lead (Pb)-free) Si4825DY-T1-GE3 (Lead (Pb)-free and Halogen-free)

ABSOLUTE MAXIMUM RATINGS	$T_A = 25 \ ^{\circ}C$, unles	ss otherwise r	noted		
Parameter		Symbol	10 s	Steady State	Unit
Drain-Source Voltage		V _{DS}	- 30		V
Gate-Source Voltage		V _{GS}	± 25		
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 25 °C	– I _D	- 11.5	- 8.1	
	T _A = 70 °C		- 9.2	- 6.5	
Pulsed Drain Current		I _{DM}	- 50		A
Continuous Source Current (Diode Conduction) ^a		۱ _S	- 2.5	- 1.3	
Maximum Power Dissipation ^a	T _A = 25 °C	Р	3.0	1.5	
	T _A = 70 °C	PD	1.9	0.9	W
Operating Junction and Storage Temperature Range		T _J , T _{stq}	- 55 to 150		°C

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
	t ≤ 10 s	R _{thJA}	32	42	
Maximum Junction-to-Ambient ^a	Steady State		68	85	°C/W
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	15	18	

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

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SPECIFICATIONS $T_J = 25 \text{ °C}$, unless otherwise noted							
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = -250 \ \mu A$			- 3.0	V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V$, $V_{GS} = \pm 25 V$			± 100	nA	
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = -30 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			- 1	μA	
		$V_{DS} = -30$ V, $V_{GS} = 0$ V, $T_{J} = 55$ °C			- 5		
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \le$ - 5 V, V_{GS} = - 10 V	- 50			А	
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = - 10 V, I _D = - 11.5 A		0.012	0.014	Ω	
		V _{GS} = - 4.5 V, I _D = - 9.2 A		0.018	0.022		
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 15 V, I _D = - 11.5 A		28		S	
Diode Forward Voltage ^a	V _{SD}	$I_{\rm S}$ = - 2.5 A, $V_{\rm GS}$ = 0 V		- 0.8	- 1.2	V	
Dynamic ^b							
Total Gate Charge	Qg			55	71	nC	
Gate-Source Charge	Q _{gs}	V_{DS} = - 15 V, V_{GS} = - 10 V, I_{D} = - 11.5 A		15.5			
Gate-Drain Charge	Q _{gd}			7.5		1	
Gate Resistance	R _g	f = 1 MHz		3.5	5.3	Ω	
Turn-On Delay Time	t _{d(on)}			15	25		
Rise Time	t _r	V_{DD} = - 15 V, R_L = 15 Ω		13	20	ns	
Turn-Off Delay Time	t _{d(off)}	${\rm I}_{\rm D} \cong$ - 1 A, ${\rm V}_{\rm GEN}$ = - 10 V, ${\rm R}_{\rm g}$ = 6 Ω		97	150		
Fall Time	t _f			51	75	1	
Source-Drain Reverse Recovery Time	t _{rr}	I _F = - 2.5 A, dl/dt = 100 A/μs		45	80		

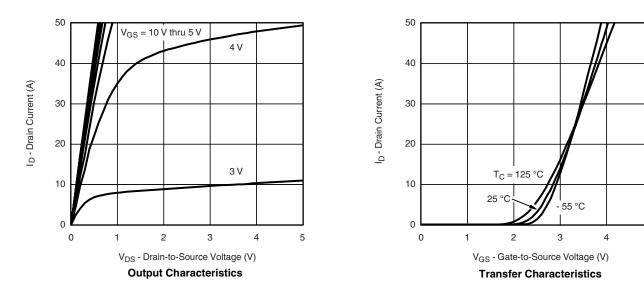
Notes:

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

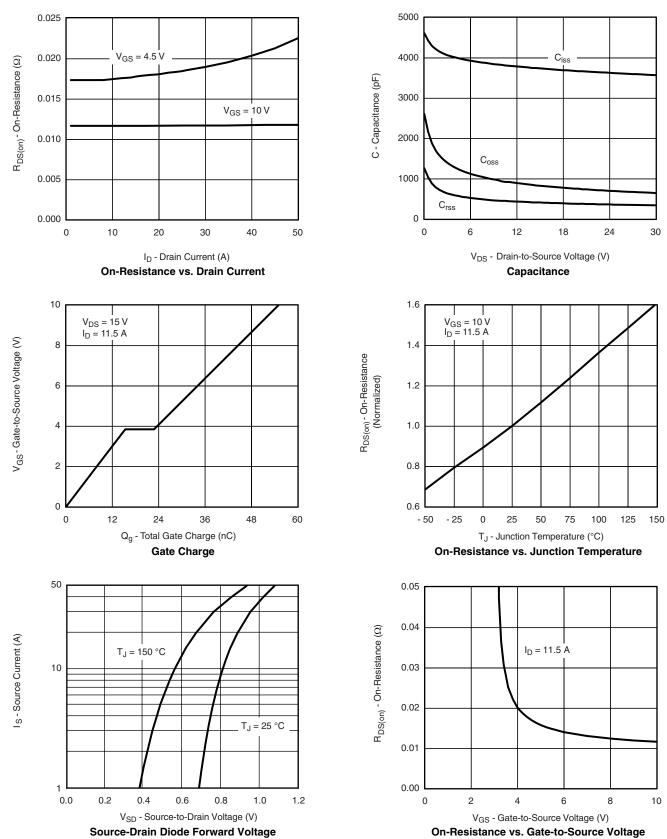


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Si4825DY Vishay Siliconix

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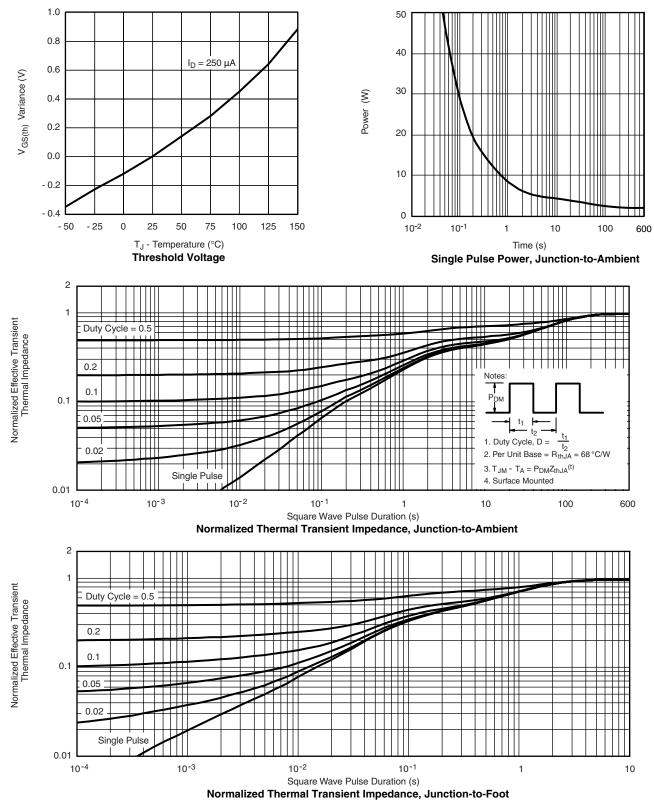
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Si4825DY

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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



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